6A, Step-down 4-cell Li+ Battery Charger IC With Photovoltaic Cell MPPT Function CN3884

General Description:

CN3884 is a step-down PWM switch-mode charger IC for 4-cell lithium-ion batteries with few external components in small footprint package.

The CN3884 is specially designed for charging 4-cell lithium ion batteries with trickle charge, constant current and constant voltage mode. In constant voltage mode, the regulation voltage is fixed at 16.8V with 1% accuracy. The constant charging current is set with an external current sense resistor.

When solar panel is used as power supply, CN3884 can automatically adjust charge current to track solar panel's maximum power point.

Deeply discharged batteries are automatically trickle charged at 25% of the full-scale charge current until the cell voltage exceeds 66.6% of regulation voltage. The charge cycle is terminated once the charge current drops to 15% of full-scale charge current, and a new charge cycle automatically restarts if battery voltage falls below 95.8% of regulation voltage. CN3884 will automatically enter sleep mode when input voltage is lower than battery voltage.

Other features include JEITA-compliant battery temperature monitoring, battery reverse current blocking, battery over voltage protection, 2 open-drain status indications, etc.

CN3884 is available in 16-pin TSSOP package.

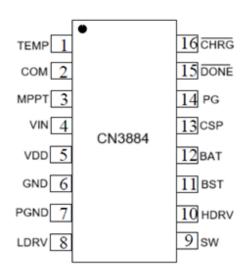
Applications:

- Robotic Cleaner
- Emergency Lighting
- Industrial and Medical Equipment
- Electric Tools
- Audio/Video Systems

Features:

- Solar Panel MPPT Function
- Standalone Charge Management for 4-cell Lithium-ion Battery
- Wide Input Voltage: 6.5V to 30V
- Charge Current up to 6A
- PWM Switching Frequency: 550KHz
- Regulation Voltage: 16.8V±1%
- Charge Current is externally set
- Automatic Conditioning of Deeply Discharged Batteries
- 100% Duty Cycle
- Automatic Recharge
- 2 Open-drain Status Indication
- JEITA-Compliant Battery Temperature Monitoring
- Built-in Soft Start
- Battery Reverse Current Blocking
- Operating Ambient Temperature
 −40°C to +85°C
- Available in TSSOP-16 Package
- Pb-free, Rohs-Compliant, Halogen Free

Pin Assignment:



Typical Application Circuit:

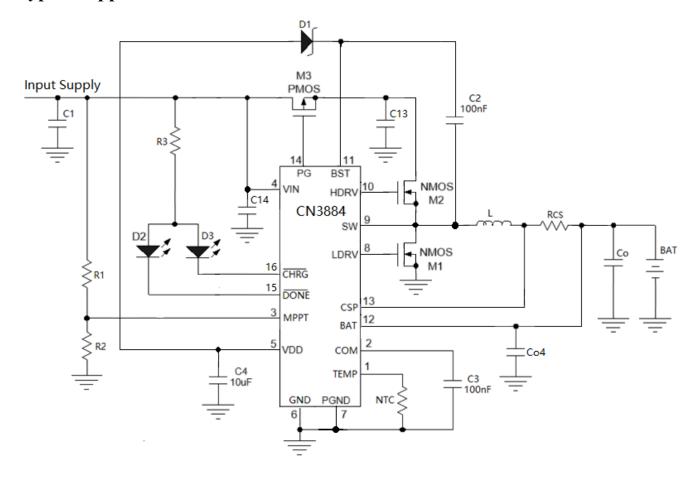


Figure 1 Typical Application Circuit

Ordering Information

Part No.	Part No. Package Top Marking		Shipping	Operating Temperature Range	
CN3884	TSSOP-10	CN3884	Tape and Reel, 4000/Reel	-40°C to +85°C	

Pin Description:

No.	Symbol	Description
		Battery Temperature Monitoring Input. Connecting a 10KΩ NTC
		thermistor between TEMP pin and GND.
		• If TEMP pin's voltage is below 0.1V or above 0.85V, which
		means battery is too hot or too cold, charging is suspended.
		• If TEMP's voltage is between 0.1V and 0.135V, which means
		battery is warm, charge current is reduced to 50% of full-scale
		current and regulation voltage is reduced to 97.91%*V _{REG}
1	TEMP	• If TEMP's voltage is between 0.135V and 0.55V, CN3884
		functions normally.
		• If TEMP's voltage is between 0.55V and 0.85V, which means
		battery is cool, charge current is reduced to 25% of constant
		current.
		If battery temperature monitoring function is not needed, connect a
		fixed 10K ohm resistor from TEMP pin to GND.
		Loop Compensation Pin. Connect a 100nF capacitor from COM
2	COM	pin to GND to stabilize current and voltage regulation loops.
		Photovoltaic Cell Maximum Power Point Tracking Pin. Connect
2	MPPT	MPPT pin to the external resistor divider for maximum power point
3		tracking. In maximum power point tracking mode, the MPPT pin's
		voltage is regulated to 1.205V.
4	VIN	DC Power Supply Input. VIN is the power supply for internal
4		circuit. Filtering capacitors are needed between VIN and GND.
		5V Voltage Regulator (LDO) Output. Connect a 10uF capacitor
5	VDD	from VDD to GND. The maximum output current of the 5V LDO is
3	VDD	15mA. The 5V voltage can also be used to power the external
		circuitry in addition to powering the internal circuit.
6	GND	Analog Ground (GND).
7	PGND	Power Ground (PGND).
		The Gate Drive Pin for Low-side N-channel MOSFET. Connect
8	LDRV	to the gate of external low-side N-channel MOSFET, namely M1 in
		Figure 1.
0	CW	Inductor Connection Pin. Connect to one of inductor terminals,
9	SW	namely switching node as shown in Figure 1.
		The Gate Drive Pin for High-side N-channel MOSFET. Connect
10	HDRV	to the gate of external high-side N-channel MOSFET, namely M2 in
		Figure 1.
		The Power Supply of Driving Circuit for High-side N-channel
		MOSFET. A bootstrap capacitor of 100nF needs to be connected
11	BST	between BST pin and switching node. Also a schottky diode like
		SS24 is needed to be connected between BST pin and VDD pin (5V
		LDO output).

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No.	Symbol	Description
	BAT	Battery Voltage Sensing Input and the Negative Terminal for
12		to positive terminal of battery to sense battery voltage. BAT pin and
		the CSP pin measure the voltage drop across current sense resistor
		R _{CS} to regulate charge current.
		Positive Input for Charge Current Sensing. CSP pin and the BAT
1.2	CCD	pin measure the voltage drop across current sense resistor $R_{\rm CS}$ to
regulate charge current. In constant curr	regulate charge current. In constant current mode, (CSP-BAT) is	
		regulated at 100mV.
		The Gate Drive for External P-channel MOSFET. As shown in
	PG	Figure 1, PG pin should be connected to gate of external P-channel
14		MOSFET. The P-channel MOSFE is used to prevent reverse current
14		from battery when input supply is absent or is lower than battery
		voltage.
		If the P-channel MOSFET is not used, leave PG pin floating.
		Open-Drain Termination Status Indication Output. When
15	DONE	charging is terminated, this pin is pulled low to GND by an internal
		Battery Voltage Sensing Input and the Negative Terminal of Charge Current Sensing. Externally BAT pin should be connect to positive terminal of battery to sense battery voltage. BAT pin a the CSP pin measure the voltage drop across current sense resist R _{CS} to regulate charge current. Positive Input for Charge Current Sensing. CSP pin and the BA pin measure the voltage drop across current sense resistor R _{CS} regulate charge current. In constant current mode, (CSP-BAT) regulated at 100mV. The Gate Drive for External P-channel MOSFET. As shown Figure 1, PG pin should be connected to gate of external P-channel MOSFET. The P-channel MOSFE is used to prevent reverse curre from battery when input supply is absent or is lower than batte voltage. If the P-channel MOSFET is not used, leave PG pin floating. Open-Drain Termination Status Indication Output. When charging is terminated, this pin is pulled low to GND by an interreswitch. Otherwise this pin is in high impedance state. Open-Drain Charge Status Indication Output. When the batter is being charged, this pin is pulled low to GND by an interrespondent of the properties of the
		Open-Drain Charge Status Indication Output. When the battery
16	CHRG	is being charged, this pin is pulled low to GND by an internal
		switch. Otherwise this pin is in high impedance state.

ABSOLUTE MAXIMUM RATINGS

Voltage from VIN to GND0.3V to 32V	Maximum Junction Temperature150℃
Voltage from CHRG to GND−0.3V to 32V	Operating Temperature Range—40°C to 85°C
Voltage from DONE to GND−0.3V to 32V	Storage Temperature -65° C to 150° C
Voltage from SW to GND $-0.3V$ to $32V$	Lead Temperature(Soldering,10s)260 ℃
Voltage from CSP, BAT to GND -0.3 V to 32V	Thermal Resistance(TSSOP16)200°C/W
Voltage from BST, HDRV to SW0.3V to 6.5V	Voltage from MPPT to GND $-0.3V$ to $6.5V$
Voltage from PG to GND $-0.3V$ to BAT+0.3V	
Voltage from VDD to GND0.3V to 6.5V	Voltage from TEMP to GND0.3V to VDD+0.3V
Voltage from COM to GND $-0.3V$ to VDD+ $0.3V$	Voltage from MPPT to GND $-0.3V$ to VDD+ $0.3V$
Voltage from LDRV to GND 0.3V to VDD+0.3V	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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ELECTRICAL CHARACTERICS:

 $(\text{VIN} = 18\text{V}, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}, \text{Typical values are at } T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}))$

Parameters	Symbol	Test Co	nditions	Min	Тур	Max	Unit	
Input Voltage Range	VIN					30	V	
Under Voltage Lockout Threshold	UVLO			3.8	5	6.3	V	
Operating Current	I _{VIN}	$V_{BAT}>V_{REG},$	No Switching	535	672	810	uA	
DAT Div. Comment	I_{BAT1}	Termination,	$V_{BAT} = 17V$	8	12	16	uA	
BAT Pin Current	I _{BAT2}	Sleep mode, V	$V_{\rm BAT} = 15 V$	2.8	4.4	6		
Regulation Voltage	3.7	Normal batter	ry temperature	16.635	16.8	16.968	V	
(Constant Voltage Mode)	V_{REG}	Battery warm	1	16.28	16.45	16.62		
CI C + C		$V_{BAT}>V_{PRE}$		88	100	112		
Charge Current Sense	V_{CS}	$V_{BAT}>V_{PRE}$	Battery warm	37	47	57	mV	
Measure $(V_{CSP} - V_{BAT})$		V _{BAT} <v<sub>PRE,0</v<sub>	r Battery cool	15	25	35		
Trickle Charge								
Precharge Threshold	V _{PRE}	BAT Voltage	rises	64	66.6	69	$%V_{REG}$	
Hysteresis	H _{PRE}	BAT Voltage	falls		2.5		%V _{REG}	
Charge Termination								
Termination Threshold	I _{term}	Charge Curre	nt Falls	10	15	20	%I _{CC}	
Recharge								
D 1 T1 1 11	V_{RE}	BAT falls		93	95.8	98.6	%V _{REG}	
Recharge Threshold		BAT falls, Ba	attery warm	88.5	91.6	94.7		
BAT Pin Over Voltage Pr	BAT Pin Over Voltage Protection							
Over Voltage Threshold	Vov	BAT Voltage rises		1.036	1.068	1.1		
Over Voltage Release Threshold	Velr	BAT Voltage falls		1.0	1.024	1.049	V_{REG}	
MPPT Pin				•				
Regulation Voltage	V_{MPPT}	MPP Tracking	g Mode	1.18	1.205	1.23	V	
Bias Current	I_{MPPT}			-100	0	100	nA	
Oscillator				•				
Frequency	fosc			430	550	670	kHZ	
Maximum Duty Cycle	Dmax					100	%	
Sleep Mode				•				
Sleep Mode Threshold	17	A/INT C 11	W _10V	0.0	0.05		***	
Measure (VIN-V _{BAT})	V_{SLP}	VIN falls	$V_{BAT}=16V$	0.0	0.05	0.1	V	
Sleep Mode Release					0.25	0.39	V	
Threshold	V_{SLPR}	VIN rises	$V_{BAT}=16V$	0.13				
Measure (VIN-V _{BAT})								
Junction Over Temperature Protection								
Over Temperature	т	Transit 4-			1.45		00	
Protection Threshold	T_{OTP}	Junction temperature rises		145		°C		
Over Temperature	т	Junction temperature falls			120		°C	
Release Threshold	T_{RLS}	Junetion temp	ociature lans		128			

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Parameters	Symbol	Test Conditions	Min	Тур	Max	Unit	
LDRV Pin	•		•		1		
Output High	V _{Hpin8}	$I_{DRV} = -10 \text{mA}$	VDD-0.03	5		V	
Output Low	V_{Lpin8}	I _{DRV} =+10mA			0.04	V	
Rise Time	t_{rpin8}	Cload=2nF, 10% to 90%	30	40	60	nS	
Fall Time	t _{fpin8}	Cload=2nF, 90% to 10%	18	25	35	nS	
HDRV Pin							
Output High	V_{Hpin10}	$I_{DRV} = -10 \text{mA}$	BST-0.05			V	
Output Low	V_{Lpin10}	I _{DRV} =+10mA			SW+0.04	V	
Rise Time	t _{rpin10}	Cload=2nF, 10% to 90%	30	40	60	nS	
Fall Time	tfpin10	Cload=2nF, 90% to 10%	20	30	45	nS	
TEMP Pin							
TEMP Current	ITEMP		27	30	33	uA	
Cold Threshold	V _{COLD}	V _{TEMP} rises, cool to cold	800	850	900	mV	
Cold Release Threshold	V _{COLDR}	V _{TENP} falls, cold to cool	755	805	855	mV	
Cool Threshold	V_{COOL}	V _{TEMP} rises, normal to cool	510	550	590	mV	
Cool Release Threshold	V_{COOLR}	V _{TENP} falls, cool to normal	465	505	545	mV	
Warm Threshold	V _{WARM}	V_{TENP} falls, normal to warm	120	135	150	mV	
Warm Release Threshold	V_{WARMR}	V _{TEMP} rises, warm to normal	138	155	172	mV	
Hot Threshold	V_{HOT}	V _{TENP} falls, warm to hot	85	100	115	mV	
Hot Release Threshold	V_{HOTR}	V _{TEMP} rises, hot to warm	105	120	135	mV	
PG Pin							
Output High	V_{PGH}	Sleep mode		BAT		V	
O-+ I	17	Normal operation, VIN<12V	0			V	
Output Low	$ m V_{PGL}$	Normal operation, VIN>12V	VIN-12			V	
Pull-up Current	I _{PGSRC}	Sleep mode, V _{BAT} =15V V _{BAT} -V _{PG} =0.2V	0.75	1	1.25	mA	
CHRG Pin	·	•	·		<u> </u>		
CHRG Sink Current	Ichrg	V _{CHRG} =1V, charge mode	7	12	18	mA	
CHRG Leakage Current	I_{LK1}	V _{CHRG} =30V, termination			1	uA	
DONE Pin							
DONE Sink Current	I _{DONE}	V _{DONE} =1V, termination	7	12	18	mA	
DONE Leakage Current	I_{LK2}	V _{DONE} =30V, charge mode			1	uA	

注: V_{REG} is the regulated voltage in constant voltage mode; I_{CC} is the charge current in constant current mode.

Detailed Information:

CN3884 is a constant current, constant voltage battery charger controller IC that can be powered by the photovoltaic cell with maximum power point tracking function. The CN3884 adopts PWM step-down switching architecture, and is specially designed to charge 4-cell Lithium ion batteries. The charge current is set by an external current sense resistor (R_{CS}) across the CSP and BAT pins. The final battery regulation voltage in constant voltage mode is internally fixed at 16.8V with 1% accuracy.

A charge cycle begins when the voltage at the VIN pin rises above the UVLO level and is greater than the battery voltage by V_{SLPR} . At the beginning of the charge cycle, if the battery voltage is less than 66.6% of regulation voltage (V_{REG}), the charger goes into trickle charge mode. The trickle charge current is internally set to 25% (Typical) of the full-scale charge current. When the battery voltage exceeds 66.6% of regulation voltage, the charger goes into the full-scale constant current charge mode. In constant current mode, the charge current is set by the external sense resistor R_{CS} and an internal 100mV reference, the charge current equals to 100mV/ R_{CS} . When the battery voltage approaches the regulation voltage, the charger goes into constant voltage mode, and the charge current will start to decrease. When the charge current drops to 15% of the full-scale charge current, the charge cycle is terminated, \overline{CHRG} pin outputs high impedance and \overline{DONE} pin is pulled down to GND to indicate the termination status. To restart the charge cycle, just remove and reapply the input supply. Also, a new charge cycle will begin if the battery voltage falls below the recharge threshold of 95.8% of the regulation voltage in constant voltage mode. The CN3884 adopts the constant voltage method to track the photovoltaic cell's maximum power point. The MPPT pin's voltage is regulated to 1.205V to track the maximum power point of the photovoltaic cell.

When the input supply is not present, the charger automatically goes into sleep mode, all the internal circuits are shutdown.

An over-voltage comparator guards against voltage transient overshoots (>6.8% of regulation voltage). In this case, both 2 external N-channel MOSFET is turned off until the overvoltage condition is cleared. This feature is useful for battery load dump or sudden removal of battery.

The charging profile is shown in Figure 2.

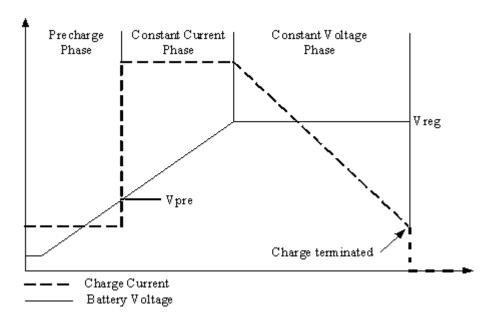


Figure 2 Charging Profile

Application Information

Under voltage Lockout (UVLO)

An under-voltage lockout circuit monitors the input voltage and keeps the charger off if VIN falls below 6.3V (Maximum).

Trickle Charge Mode

At the beginning of a charge cycle, if the battery voltage is below 66.6% of the regulation voltage, the charger goes into trickle charge mode with the charge current reduced to 25% of the full-scale charge current.

Charge Current Setting

The full-scale charge current, namely the charge current in constant current mode, is decided by the following formula:

$$ICH = \frac{100mV}{RCS}$$

Where:

I_{CH} is the full scale charge current

R_{CS} is the current sense resistor between the CSP pin and BAT pin

The Maximum Power Point Tracking

CN3884 adopts the constant voltage method to track the photovoltaic cell's maximum power point. From I-V curve of photovoltaic cell, under a given temperature, the photovoltaic cell's voltages at the maximum power point are nearly constant regardless of the different irradiances. So the maximum power point can be tracked if the photovoltaic cell's output voltage is regulated to a constant voltage.

CN3884's MPPT pin's voltage is regulated to 1.205V to track the maximum power point working with the off-chip resistor divider (R1 and R2 in Figure 1).

The maximum power point voltage is decided by the following equation:

$$V_{MPPT} = 1.205 \times (1 + R1 / R2)$$

Charge Termination

In constant voltage mode, the charge current decreases gradually. When the charge current decreases to 15% of the full-scale charge current, the charging is terminated. In charge termination mode, $\overline{\text{CHRG}}$ pin outputs high impedance and $\overline{\text{DONE}}$ pin is pulled down to GND to indicate the charge termination mode. In termination mode, both the external N-channel MOSFETs are turned off, no current flows to battery.

In photovoltaic cell's maximum power point tracking mode, the charging will not be terminated until the battery voltage is higher than 95.8% of the regulation voltage, even though the charge current is lower than 15% of the full-scale charge current. Namely to terminate charging, the battery voltage has to be higher than 95.8% of the regulation voltage, and charge current is lower than 15% of the full-scale charge current.

Automatic Recharge

After the charge cycle is completed and both the battery and the input power supply (wall adapter) are still present, a new charge cycle will begin if the battery voltage falls below 95.8% of the regulation voltage in constant voltage mode.

Battery Temperature Monitoring

To prevent the damage caused by the very high or very low temperature done to the battery, the CN3884 continuously monitor battery temperature by measuring the voltage at TEMP pin which is determined by TEMP pin's source current (30uA typical) and a $10K\Omega$ negative temperature coefficient (NTC) thermistor connected between TEMP pin and GND as shown in Figure 1.

If battery temperature monitoring function is not needed, connect a fixed $10K\Omega$ resistor from TEMP to GND.

The battery temperature monitoring function for CN3884 is designed to follow the JEITA standard; charge current or charge termination voltage is reduced based on battery temperature ranges.

There are totally five battery temperature ranges for CN3884:

Hot: Above 55°C,
Warm: 45°C to 55°C,
Normal: 10°C to 45°C
Cool: 0°C to 10°C,
Cold: Below 0°C.

Normal operation occurs when battery temperature is between 10°C and 45°C, charge current and voltage will be the normal values.

When battery is in the Cool temperature range, which is between 0°C and 10°C, the charge current is 25% of full-scale charge current and regulation voltage is not changed.

When the battery is in the Warm temperature range, which is between 45°C and 55°C, the charge current is reduced to 50% of full-scale charge current and regulation voltage is reduced to 97.91% of nominal value.

Charging is suspended if battery temperature is below Cold temp of 0°C or above Hot temp of 55°C. When charging is suspended, both CHRG and DONE pin becomes high impedance state.

Once battery temperature is not in hot range and cold range, charging resumes automatically.

TEMP pin voltage is the product of its source current and NTC's resistance, so the selection of NTC should make sure TEMP pin voltage meet the requirements of hot, warm, cool and cold threshold. An NTC of nominal resistance $10K\Omega$ at room temperature may be suitable for CN3884.

A resistor of small resistance in series with NTC thermistor and a resistor of large resistance in parallel with NTC thermistor can fine tune CN3884's temperature range.

The following table lists TEMP pin voltage, charge current and termination voltage in the above-mentioned 5 battery temperature range.

Battery Temperature Range	TEMP Pin Voltage	Charge Current	Regulation Voltage
Hot: above 55°C	$V_{TEMP} < V_{HOT}$	Charge Suspended	Charge Suspended
Warm: 45°C to 55°C	$V_{HOTR} < V_{TEMP} < V_{WARM}$	50%*I _{CC}	97.91%*V _{REG}
Normal: 10°C to 45°C	$V_{WARMR} < V_{TEMP} < V_{COOLR}$	Normal Value	Normal Value
Cool: 0°C to 10°C	$V_{COOL} < V_{TEMP} < V_{COLDR}$	25%*I _{CC}	Normal Value
Cold: below 0°C	V _{TEMP} >V _{COLD}	Charge Suspended	Charge Suspended

Status Indication

The CN3884 has 2 open-drain status output: CHRG and DONE. CHRG pin is pulled down to GND when charger is in charging status, otherwise CHRG becomes high impedance. In termination status, DONE is pulled down to GND. When the battery is not present, the charger charges the output capacitor to regulation voltage or the over-voltage protection threshold quickly, CN3884 enters termination mode or over-voltage protection mode, then battery voltage decays slowly to recharge threshold or over-voltage release threshold because of discharge by the feedback resistors, CN3884 enters charge mode, and the output capacitor is charged to regulation voltage or over-voltage protection threshold again, and so forth. Then a ripple waveform is formed at charger's output, namely battery positive terminal,

in the meantime, \overline{CHRG} pin outputs high impedance, \overline{DONE} pin outputs pulse to indicate the battery's absence. The \overline{CHRG} and \overline{DONE} pin should be tied to ground if not used.

The table 1 lists the indicator status and its corresponding charging status. It is supposed that red LED is connected to $\overline{\text{DONE}}$ pin and green LED is connected to $\overline{\text{DONE}}$ pin.

CHRG Pin	DONE Pin	Description	
Low (Red LED ON)	High Impedance (Green LED OFF)	Charging Status	
High Impedance (Red LED OFF)	Low (Green LED ON) Termination Sta		
		There are 3 Possible Reasons:	
High Immediance (Bod LED OFF)	High Immediance (Cross LED OFF)	• VIN <v<sub>UVLO, or</v<sub>	
High Impedance (Red LED OFF)	High Impedance (Green LED OFF)	• VIN \leq V _{BAT} , or	
		Battery Hot or Cold	

Table 1 Status Indication

Preventing Reverse Current from Battery

In the application circuit shown in Figure 1, if there is no P-channel MOSFET M3, when input supply is absent or input supply voltage is less than battery voltage, the current flows back from battery to input supply via inductor and body diode of N-channel MOSFET M2, the reverse current may drain the battery, or damage input supply. So the P-channel MOSFET M3 is adopted to prevent the reverse current from battery.

When input supply is absent or input supply voltage is less than battery voltage, CN3884 enters sleep mode, PG pin is pulled up to voltage level as same as battery, P-channel MOSFET M3 is turned off, hence the reverse current from battery is blocked.

In normal operation mode, the P-channel MOSFET M3 remains in on state, since the on-resistance of the P-channel MOSFET can be chosen low enough, the converter's efficiency will not be degraded significantly.

If the P-channel MOSFET is not used, PG pin can be left floating.

A schottky diode can be used to replace the P-channel MOSFET, but special consideration should be given to the diode's forward voltage drop and power dissipation.

Loop Compensation

In order to make sure that the current and the voltage regulation loops are stable, an 100nF ceramic capacitor from the COM pin to GND is necessary.

Input Supply Bypassing Capacitors

To ensure CN3884's proper operation, at least 2 bypassing capacitors are needed at input supply.

The first capacitor is for the bypassing of CN3884's VIN pin (Pin 4), C14 in Figure 1 is the capacitor. A ceramic capacitor of at least 1uF for C14 can meet the requirement. In PCB design, C14 should be placed as close as possible to VIN pin (Pin 4).

The second and third capacitor (C1 and C13 in Figure 1) are assumed to absorb all input switching ripple current in the converter, it must have an adequate ripple current rating. Worst-case RMS ripple current is approximately one-half of charge current. Generally a 10uF capacitor for C1 is sufficient.

In order to depress the high-frequency oscillation during N-channel MOSFET's turning on and off, it is best that the input bypassing capacitor C13 consists of the following 3 capacitors in parallel:

- Electrolytic capacitor for low-frequency filtering
- A ceramic capacitor from 1uF to 10uF
- A high-frequency capacitor from 47nF to 1uF

In PCB design, capacitor C1 should be placed as close as possible to drain of P-channel MOSFET M3 in Figure 1. C13 should be placed very close to N-channel MOSFET M2's drain and M1's source.

Inductor Selection

During high-side N-channel MOSFET's on time, the inductor current increases, and decreases during low-side N-channel MOSFET's off time, the inductor's ripple current increases with lower inductance and higher input voltage. Higher inductor ripple current results in higher charge current ripple and greater core losses. So the inductor's ripple current should be limited within a reasonable range.

The inductor's ripple current is given by the following formula:

$$\triangle I_L = \frac{1}{(f)(L)} V_{BAT} (1 - \frac{V_{BAT}}{VIN})$$

Where, f is the switching frequency 550KHz

L is the inductor value

V_{BAT} is the battery voltage

VIN is the input voltage

A reasonable starting point for setting inductor ripple current is $\triangle I_L \leq 0.3 \times I_{CH}$, I_{CH} is the charge current. Remember that the maximum $\triangle I_L$ occurs at the maximum input voltage and the lowest inductor value. So lower charge current generally calls for larger inductor value.

So the inductor value should meet the requirement of the following formula:

$$L \geqslant \frac{VBAT*(VIN - VBAT)}{0.3*ICH*f*VIN}$$

If solar panel is used as the input supply, the inductor value should be increased accordingly.

Output Capacitors

To ensure CN3884's proper operation, at least 2 bypassing capacitors are needed at output.

The first capacitor is for the bypassing of CN3884's BAT pin (Pin 12), this capacitor is to ensure the correct sampling of battery voltage and charge current, C_{04} in Figure 1 is the capacitor. A ceramic capacitor of at least 1uF for C_{04} can meet the requirement. In PCB design, C_{04} should be placed as close as possible to BAT pin (Pin 12). The second capacitor (Co in Figure 1) is used to minimize ripple voltage and load step transients, so the ceramic capacitor with low ESR should be selected.

If only ceramic capacitor is used, cares must be taken that some ceramic capacitors exhibit large voltage coefficient, which may lead to high voltage at BAT pin when battery is not present. In this case, the capacitor value should be increased properly so that no damage will be done.

In order to make closed loop stable, the actual output capacitance should also meet the requirement of the following formula:

$$\frac{175}{L} \leqslant Co \leqslant \frac{400}{L}$$

Where, Co is in uF

L is the inductance calculated in the above section of "Inductor Selection", its unit is uH.

The Selection of N-channel MOSFET

CN3884 needs 2 external N-channel MOSFETs as power switch, M1 and M2 in Figure 1 are the 2 N-channel MOSFETs. The following 5 parameters should be considered carefully while selecting the 2 N-channel MOSFETs:

• Turn-on voltage Vth

The supply voltage of driving the 2 N-channel MOSFETs is internally fixed at 5V(Typical), the turn-on voltage of the 2 N-channel MOSFETs should be low enough so that the 2 N-channel MOSFETs can be fully turned on when driving voltage is 5V.

• Turn-on-resistance Rds(on)

The on-resistance Rds(on) should meet the requirement of the following formula:

$$30 \text{mV} < \text{Rds(on)} \times I_{CH} < 55 \text{mV}$$

• Total gate charge Qg and Reverse transfer capacitance C_{RSS}

On the condition that on resistance Rds(on) meet the above formula's requirement, the total gate charge Qg and reverse transfer capacitance C_{RSS} should be chosen as small as possible to reduce switching losses.

• Drain-source breakdown voltage BVdss

The 2 N-channel MOSFETs' drain-source breakdown voltage BVdss should be greater than input supply voltage plus a safe margin. For example, if input supply voltage is 20V, it is better that the 2 N-channel MOSFETs have a BVdss of 30V. For 30V input supply voltage, the BVdss of 40V is a good choice.

• Continuous drain current I_D

The continuous drain current of the 2 N-channel MOSFETs should be chosen according to the following formula:

$$I_D > = 1.5 \times I_{CH} \times V_{BAT} / VIN$$

In the above formulas, I_{CH} is the full-scale charge current, V_{BAT} is battery voltage, VIN is input voltage.

The Selection of P-channel MOSFET

The CN3884 needs an external P-channel MOSFET (M3 in Figure 1) to prevent reverse current from battery. The P-channel MOSFET is in on state in normal operation, only in sleep mode the P-channel MOSFET is turned off. The following 4 parameters should be considered carefully while selecting the P-channel MOSFET:

• Turn-on resistance Rds(on)

The on-resistance Rds(on) of the P-channel MOSFET should be chosen as small as possible to reduce conduction loss. It is best that the on-resistance Rds(on) can meet the requirement of the following equation:

$$Rds(on) \times I_{CH} < 55mV$$

Maximum gate-source voltage

The maximum gate-source voltage of the P-channel MOSFET should be no less than 12V.

• Source-drain breakdown voltage BVdss

The P-channel MOSFET's source-drain breakdown voltage BVdss should be greater than input supply voltage plus a safe margin. For example, if input supply voltage is 20V, it is better that the P-channel MOSFET has a BVdss of 30V. For 30V input supply voltage, the BVdss of 40V is a good choice.

Continuous drain current Id

The continuous drain current of the P-channel MOSFET should meet the requirement of the following formula:

$$I_D >= 1.5 \times I_{CH} \times V_{BAT} / VIN$$

Where, I_{CH} is the full-scale charge current, V_{BAT} is the battery voltage, VIN is the input voltage.

In most cases, P-channel MOSFET CN30P14 can meet the above requirement.

The Case of Input Supply Voltage Being Greater Than 20V

When the input supply voltage is greater than 20V, to depress the transient voltage overshoot, the application circuit shown in Figure 3 should be adopted, in which a 4.7 ohm resistor between input supply and CN3884 VIN pin (Pin 4) is added, also C14 in Figure 14 should be 10uF at least.

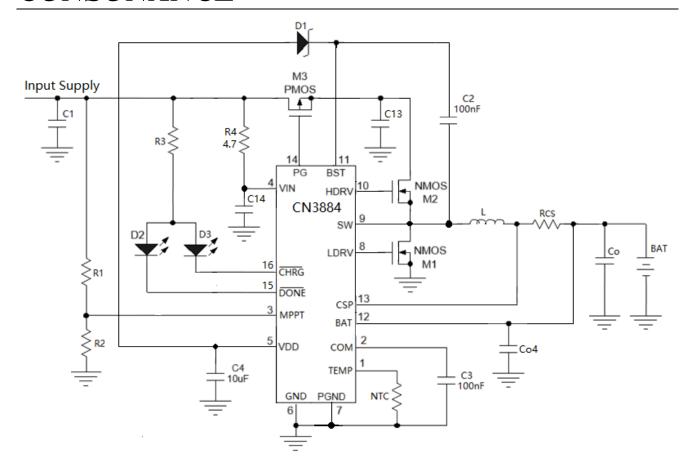


Figure 3 Add R4 for Input Supply Voltage Being Greater Than 20V

PCB Lavout Considerations

A good printed circuit board design is very critical for the proper operation of DC-DC converter. When laying out the printed circuit board, it is essential to follow the below priority list:

- (1) At least 3 bypassing capacitors are needed for input supply. The first one (C14 in Figure 1) should be placed as close as possible to VIN pin (Pin 4), its grounding terminal should be tied to analog GND. The second capacitor (C1 in Figure 1) should be placed as close as possible to drain of P-channel MOSFET M3. The third capacitor C13 should be placed as close as possible to N-channel MOSFET M2s drain and M1's source.
- (2) The bypassing capacitor at Pin 5 (VDD pin) should be placed as close to Pin 5 as possible, its grounding terminal should be tied to analog GND.
- (3) At least 2 bypassing capacitors are needed for output. The first one (C_{O4} in Figure 1) should be placed as close as possible to BAT pin (Pin 12), its grounding terminal should be tied to analog GND. The second capacitor (Co in Figure 1) should be placed as close as possible to current sense resistor R_{CS} .
- (4) To minimize radiation, the input supply bypassing capacitor, P-channel MOSFET, the 2 N-channel MOSFETs, inductor, current sense resistor and output capacitor traces should be kept as short as possible. Especially the connection between the inductor and the 2 N-channel MOSFETs should also be kept as short as possible.
- (5) The grounding terminal of NTC, compensation capacitor connected at the COM pin and the resistor divider at MPPT pin should be connected to analog GND of the CN3884. This will prevent ground noise from disrupting the loop stability. Place R1,R2 and C3 as close to the CN3884 as possible.
- (6) Output capacitor ground and rectifier N-channel MOSFET (M1 in Figure 1) ground connections need to feed into same copper that connects to the input capacitor ground before tying back into system ground. This ground is power ground, and should be wide enough, as wide as possible.

- (7) Analog ground and power ground (or switching ground) should return to system ground separately.
- (8) The ground pins also work as a heat sink, therefore use a generous amount of copper around the ground pins. This is especially important for high VIN and/or high gate capacitance applications.
- (9) The CSP and BAT pins should be connected directly to the 2 terminals of current sense resistor (Kelvin sensing) for best charge current accuracy. See Figure 4 as an example.

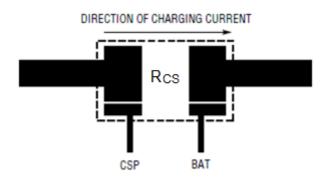
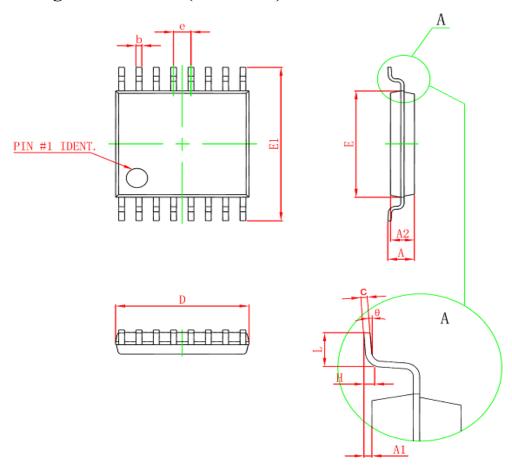


Figure 4 Kelvin Sensing of Charge Current

Package Information (TSSOP16)



Symbo1	Dimensions Ir	Millimeters	Dimensions In Inches		
3 y 111 00 1	Min	Max	Min	Max	
D	4.900	5.100	0.193	0.201	
E	4.300	4.500	0.169	0.177	
b	0.190	0.300	0.007	0.012	
С	0.090	0.200	0.004	0.008	
El	6. 250	6.550	0.246	0.258	
A		1.100		0.043	
A2	0.800	1.000	0.031	0.039	
Al	0.020	0.150	0.001	0.006	
e	0.65	(BSC)	0, 026	(BSC)	
L	0.500	0.700	0.020	0.028	
Н	0. 25	(TYP)	0.01	(TYP)	
θ	1 °	7°	1°	7°	

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